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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/083,261	02/25/2002	Joon-Hoo Choi	8071-12 (OPP 011059US)	7814
22150 7	590 11/08/2005		EXAMINER	
F. CHAU & ASSOCIATES, LLC 130 WOODBURY ROAD			WANG, GEORGE Y	
WOODBURY.			· ART UNIT	PAPER NUMBER
	,		2871	
			DATE MAILED: 11/08/2005	5

Please find below and/or attached an Office communication concerning this application or proceeding.

AK

Advisory Action Before the Filing of an Appeal Brief

Application No.	Applicant(s)	
10/083,261	CHOI ET AL.	
Examiner	Art Unit	
George Y. Wang	2871	

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The MAILING DATE of this communication appe	ars on the cover shee	et with the correspondence add	iress
THE REPLY FILED 24 October 2005 FAILS TO PLACE THIS A	PPLICATION IN CON	DITION FOR ALLOWANCE.	
1. The reply was filed after a final rejection, but prior to or on this application, applicant must timely file one of the follow places the application in condition for allowance; (2) a No a Request for Continued Examination (RCE) in compliance time periods:	the same day as filing ring replies: (1) an ame tice of Appeal (with appeal) with 37 CFR 1.114.	a Notice of Appeal. To avoid aba endment, affidavit, or other evide peal fee) in compliance with 37 C	nce, which FR 41.31; or (3)
a) The period for reply expires 3 months from the mailing date b) The period for reply expires on: (1) the mailing date of this A no event, however, will the statutory period for reply expire la Examiner Note: If box 1 is checked, check either box (a) or (TWO MONTHS OF THE FINAL REJECTION. See MPEP 70	dvisory Action, or (2) the iter than SIX MONTHS fr b). ONLY CHECK BOX (I	om the mailing date of the final reject	ion.
Extensions of time may be obtained under 37 CFR 1.136(a). The date have been filed is the date for purposes of determining the period of extunder 37 CFR 1.17(a) is calculated from: (1) the expiration date of the set forth in (b) above, if checked. Any reply received by the Office later may reduce any earned patent term adjustment. See 37 CFR 1.704(b). NOTICE OF APPEAL	ension and the correspor hortened statutory period than three months after t	ding amount of the fee. The appropriate for reply originally set in the final Off	riate extension fee ice action: or (2) as
 The Notice of Appeal was filed on A brief in comp filing the Notice of Appeal (37 CFR 41.37(a)), or any exter a Notice of Appeal has been filed, any reply must be filed AMENDMENTS 	nsion thereof (37 CFR	41.37(e)), to avoid dismissal of the	hs of the date of ne appeal. Since
 The proposed amendment(s) filed after a final rejection, to They raise new issues that would require further corton. They raise the issue of new matter (see NOTE below (c) They are not deemed to place the application in between the content of the conte	nsideration and/or sear w);	ch (see NOTE below);	
appeal; and/or (d) They present additional claims without canceling a converse NOTE: (See 37 CFR 1.116 and 41.33(a)).			
4. 🔲 The amendments are not in compliance with 37 CFR 1.12	21. See attached Notic	e of Non-Compliant Amendment	(PTOL-324).
5. Applicant's reply has overcome the following rejection(s):			
6. Newly proposed or amended claim(s) would be all non-allowable claim(s).			_
7. For purposes of appeal, the proposed amendment(s): a) [how the new or amended claims would be rejected is prov The status of the claim(s) is (or will be) as follows: Claim(s) allowed: Claim(s) objected to: Claim(s) rejected: Claim(s) withdrawn from consideration:	_] will not be entered, rided below or appende	or b)	explanation of
AFFIDAVIT OR OTHER EVIDENCE			
 The affidavit or other evidence filed after a final action, but because applicant failed to provide a showing of good and was not earlier presented. See 37 CFR 1.116(e). 	I sufficient reasons wh	y the affidavit or other evidence i	s necessary and
9. The affidavit or other evidence filed after the date of filing entered because the affidavit or other evidence failed to o showing a good and sufficient reasons why it is necessary	vercome all rejections	under appeal and/or appellant fa	ils to provide a
 The affidavit or other evidence is entered. An explanation REQUEST FOR RECONSIDERATION/OTHER 	of the status of the cl	aims after entry is below or attack	ned.
 The request for reconsideration has been considered but See Continuation Sheet. 	does NOT place the a	pplication in condition for allowa	nce because:
12. ☐ Note the attached Information Disclosure Statement(s). (13. ☐ Other:	PTO/SB/08 or PTO-14	49) Paper No(s)	
		George Wang Examiner AU 2871 November 3, 2004	

Continuation of 11. does NOT place the application in condition for allowance because: Applicant's arguments are not persuasive. First, Applicant argues the motivation to combine Gu and Murakami. First, Applicant has no handle on the materials taught in the reference since Applicant confuses the teaching. It is the Gu reference that teaches the TFT and the Murakami that teaches the motivation to combine the a-Si:O:F. Second, Applicant asserts that Examiner's previous argument is "irrelevant" because the issue is whether using a a-Si:O:F layer to reduce band gap renders obvious its use to reduce capacitance. In response, it is noted that Applicant grossly misconstrues the issue in this case. It is not to see whether using an a-Si:O:F layer "to reduce band gap" renders obvious "reduction in capacitance." Rather, the issue is to see if an a-Si:O:F layer (with no intended function applied to it) can be combined with the TFT of Gu. In this case, it can because of the advantage of reducing band gap thickness and ultimately increases intenstiv ration, improves uniformity, and maximizes color-sensing (col. 2, lines 43-48) It is clear that this is another advantange not anticipated by this combination. With respect to claim 33, Applicant argues that none of the references teach a bottom insulating layer. Again, it is noted that just because a first insulating layer has a top and bottom layer doesn't mean that the bottom layer is insulating. For instance, perhaps the combination of the top and bottom gives it properties to make it an insulating layer. But by themselves, maybe none or even one of them could be insulating. Furthermore, Applicant asserts that a semi-conductor layer does not electrically insulate and therefore cannot be considered to be an insulating layer. However, it is noted that nowhere in the claims is "electrially" insulating used. Moveover, the Ono reference clearly teaches a low dielectric and in combination with the other reference, it would have been obvious to have that material be used as a bottom layer since one would be motivated to optimize film thickness (col. 19, lines 16-64) and according to the Dohjo reference, to reduce vulnerability to the penetration of impurity ions in the transistor to prevent deterioration (col. 3, lines 6-9; col. 2, lines 39-55). Applicant has made no attempt to address the specifics of this combination. Thus, by mere suggestion that there is no teaching in the references. alone, or in combination, do not place the application in condition for allowance.

Amon Lilles
ANDREW SCHECHTER
PRIMARY EXAMINER